

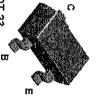
2N3906

MMBT3906

PZT3906

TO-92







PNP General Purpose Amplifier

This device is designed for general purpose amplifier and switching applications at collector currents of 10 μA to 100 mA.

Absolute Maximum Ratings*

V _{CEO} Collector-Emitter Voltage 40 V V _{CSO} Collector-Basse Voltage 40 V V _{CSO} Collector-Basse Voltage 5.0 V I _C Collector Current - Continuous 5.0 V I _C Collector Current - Continuous 200 mA T _J , T _{stg} Operating and Storage Junction Temperature Range -55 to +150 °C	Symbol	Parameter	Value	Units
Collector-Base Voltage 40 Emitter-Base Voltage 5.0 Collector Current - Continuous 200 Stg Operating and Storage Junction Temperature Range -55 to +150	VCEO	Collector-Emitter Voltage	40	<
Emitter-Base Voltage 5.0 Collector Current - Continuous 200 Sty Operating and Storage Junction Temperature Range -55 to +150	Vcso	Collector-Base Voltage	40	<
Collector Current - Continuous 200 Operating and Storage Junction Temperature Range -55 to +150	Veso	Emitter-Base Voltage	5.0	<
Operating and Storage Junction Temperature Range -55 to +150	lc	Collector Current - Continuous	200	mA
	T _J , T _{stg}	Operating and Storage Junction Temperature Range	-55 to +150	റ്

Thermal Characteristics

Symbol	Characteristic		Max		Units
		2N3906	*MMBT3906	**PZT3906	
Po	Total Device Dissipation	625	350	1,000	ΜW
	Derate above 25°C	5.0	2.8	8.0	∃W/°C
Roc	Thermal Resistance, Junction to Case	82.3			°C/W
Reja	Thermal Resistance, Junction to Ambient	200	357	125	°C/W

PNP General Purpose Amplifier

(continued)

	Symbol	Electrical
	Parameter	Electrical Characteristics
	Test Conditions	$T_{\rm A}$ = 25°C unless otherwise noted
	Min	
	Max	
1		

OFF CHARACTERISTICS Collector-Emitter Breakdown Voltage* Collector-Base Breakdown Voltage Base Cutoff Current Collector Cutoff Current Emitter-Base Breakdown Voltage V_{CE} = 30 V, V_{BE} = 3.0 V $V_{CE} = 30 \text{ V}, V_{BE} = 3.0 \text{ V}$ 40 5.0 ဗ 50 ₹ 3

ON CHAF	ON CHARACTERISTICS				
hee	DC Current Gain *	$I_{C} = 0.1 \text{ mA}, V_{CE} = 1.0 \text{ V}$	60		
		$l_c = 1.0 \text{ mA}, V_{ce} = 1.0 \text{ V}$	8		
		$ l_c = 10 \text{ mA}, V_{CE} = 1.0 \text{ V}$		300	
		$\frac{1}{10} = 50 \text{ mA}, V_{CE} = 1.0 \text{ V}$	8		
		$I_{c} = 100 \text{ mA}, V_{ce} = 1.0 \text{ V}$	မ		
VCE(sat)	Collector-Emitter Saturation Voltage	$l_c = 10 \text{ mA}, l_B = 1.0 \text{ mA}$		0.25	<
		$l_c = 50 \text{ mA}, l_B = 5.0 \text{ mA}$		0.4	<
VBE(sat)	Base-Emitter Saturation Voltage	$l_c = 10 \text{ mA}, l_B = 1.0 \text{ mA}$	0.65	0.85	<
		$l_c = 50 \text{ mA}, l_b = 5.0 \text{ mA}$	•	0.95	<

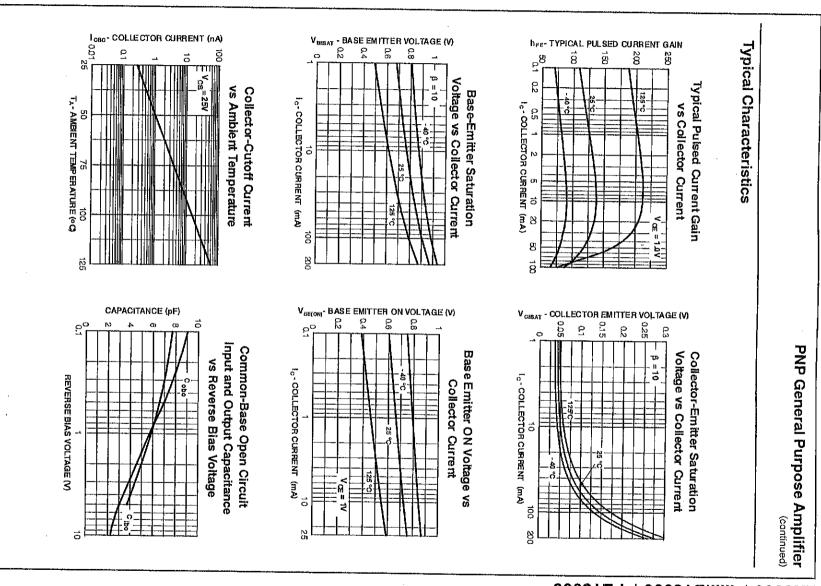
SMALLS	SMALL SIGNAL CHARACTERISTICS				
	Current Gain - Bandwidth Product	$l_c = 10 \text{ mA}, V_{CE} = 20 \text{ V},$ f = 100 MHz	250		MHz
Cobo	Output Capacitance	$V_{CB} = 5.0 \text{ V, i}_{E} = 0,$ f = 100 kHz		4.5	'n
Cibo	Input Capacitance	$V_{EB} = 0.5 \text{ V, l}_{C} = 0,$ f = 100 kHz		10.0	Ţ
<u> </u>	Noise Figure	$l_{c} = 100 \mu A$, $V_{ce} = 5.0 \text{ V}$, $R_{s} = 1.0 k\Omega$, $f = 10 \text{ Hz to } 15.7 \text{ kHz}$		4.0	8
SWITCHII	SWITCHING CHARACTERISTICS				
*	l Delay Time	- V - 100 V - 105 V		1	

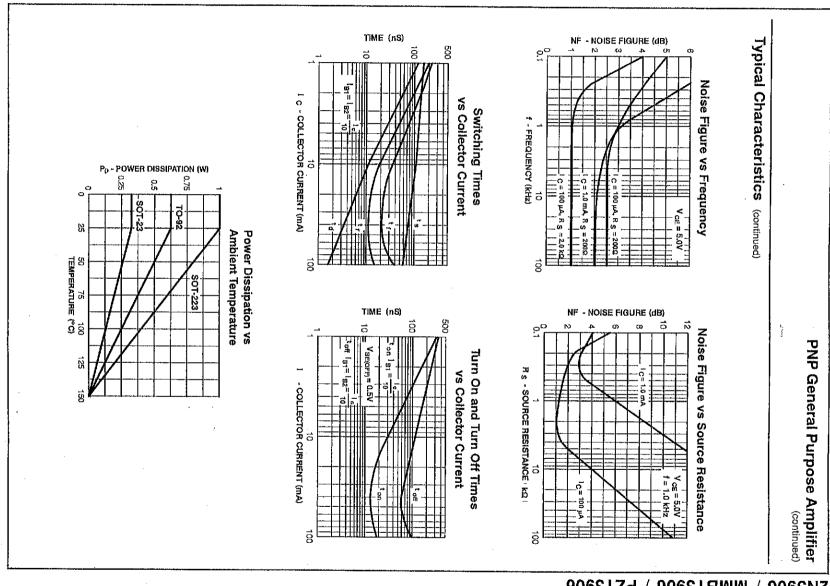
0881	OWITCH MINO CHARACTERIOTICS			
Ą.	Delay Time	$V_{CC} = 3.0 \text{ V, } V_{BE} = 0.5 \text{ V,}$	3	35 ns
ፈተ ተ	Rise Time	$l_c = 10 \text{ mA}, l_{B1} = 1.0 \text{ mA}$	3	35 ns
ś	Storage Time	$V_{CC} = 3.0 \text{ V, } I_C = 10\text{mA}$	22	225 ns
ヹ	Fall Time	$l_{\rm B1} = l_{\rm B2} = 1.0 \rm mA$	7	75 ns
*	*			

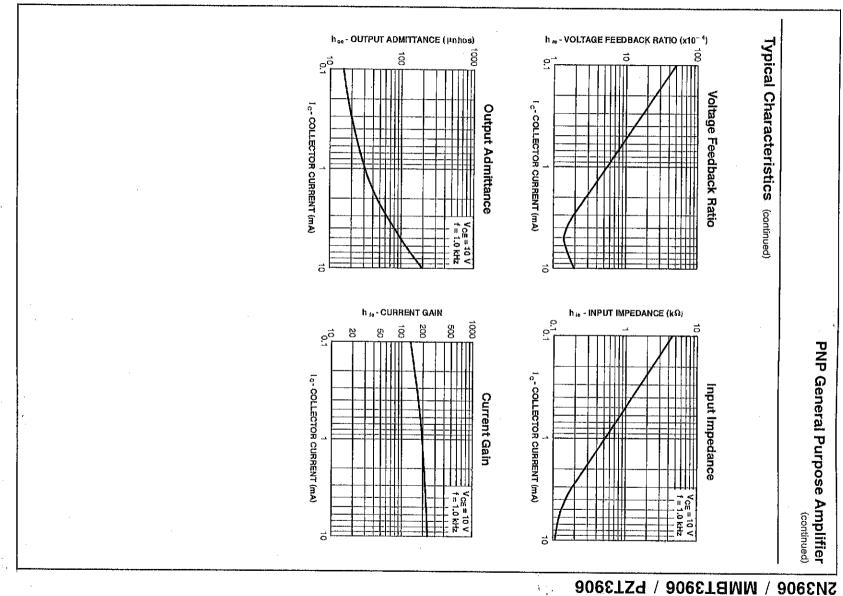
Spice Model

PNP (Is=1.41f Xtf=3 Eg=1.11 Vaf=18.7 Bf=180.7 Ne=1.5 Ise=0 Ikf=80m Xtb=1.5 Br=4,977 Nc=2 Isc=0 Ikr=0 Rc=2.5 Cjc=9.728p Mjc=.5776 Vjc=.75 Fc=.5 Cje=8.063p Mje=.3677 Vje=.75 Tr=33.42n Tf=179.3p Itf=.4 Vtf=4 Xtf=6 Rb=10)

Units







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